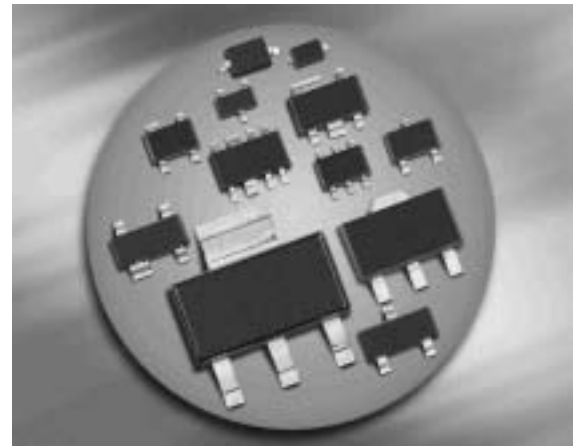
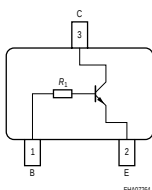


NPN Silicon Digital Transistor

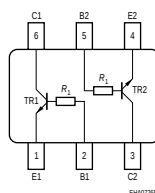
- Switching circuit, inverter, interface circuit, driver circuit
- Built in bias resistor ($R_1=10\text{ k}\Omega$)
- BCR129S: Two internally isolated transistors with good matching in one multichip package
- BCR129S: For orientation in reel see package information below
- Pb-free (RoHS compliant) package¹⁾
- Qualified according AEC Q101



BCR129/F BCR129W



BCR129S



Type	Marking	Pin Configuration						Package
BCR129	WVs	1=B	2=E	3=C	-	-	-	SOT23
BCR129F	WVs	1=B	2=E	3=C	-	-	-	TSFP-3
BCR129S	WVs	1=E1	2=B1	3=C2	4=E2	5=B2	6=C1	SOT363
BCR129W	WVs	1=B	2=E	3=C	-	-	-	SOT323

¹Pb-containing package may be available upon special request

Maximum Ratings

Parameter	Symbol	Value	Unit
Collector-emitter voltage	V_{CEO}	50	V
Collector-base voltage	V_{CBO}	50	
Input forward voltage	$V_{i(fwd)}$	40	
Input reverse voltage	$V_{i(rev)}$	5	
Collector current	I_C	100	mA
Total power dissipation- BCR129, $T_S \leq 102^\circ\text{C}$ BCR129F, $T_S \leq 128^\circ\text{C}$ BCR129S, $T_S \leq 115^\circ\text{C}$ BCR129W, $T_S \leq 124^\circ\text{C}$	P_{tot}	200 250 250 250	mW
Junction temperature	T_j	150	
Storage temperature	T_{stg}	-65 ... 150	

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point ¹⁾ BCR129 BCR129F BCR129S BCR129W	R_{thJS}	≤ 240 ≤ 90 ≤ 140 ≤ 105	K/W

¹⁾For calculation of R_{thJA} please refer to Application Note Thermal Resistance

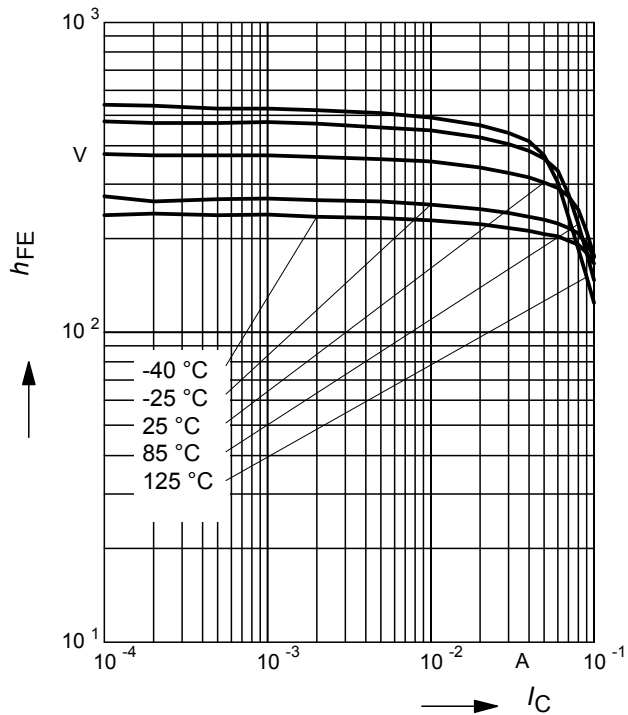
Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Collector-emitter breakdown voltage $I_C = 100\ \mu\text{A}$, $I_B = 0$	$V_{(\text{BR})\text{CEO}}$	50	-	-	V
Collector-base breakdown voltage $I_C = 10\ \mu\text{A}$, $I_E = 0$	$V_{(\text{BR})\text{CBO}}$	50	-	-	
Collector-base cutoff current $V_{\text{CB}} = 40\ \text{V}$, $I_E = 0$	I_{CBO}	-	-	100	nA
Emitter-base cutoff current $V_{\text{EB}} = 5\ \text{V}$, $I_C = 0$	I_{EBO}	-	-	100	nA
DC current gain ¹⁾ $I_C = 5\ \text{mA}$, $V_{\text{CE}} = 5\ \text{V}$	h_{FE}	120	-	630	-
Collector-emitter saturation voltage ¹⁾ $I_C = 10\ \text{mA}$, $I_B = 0.5\ \text{mA}$	V_{CEsat}	-	-	0.3	V
Input off voltage $I_C = 100\ \mu\text{A}$, $V_{\text{CE}} = 5\ \text{V}$	$V_{\text{i(off)}}$	0.4	-	1	
Input on voltage $I_C = 2\ \text{mA}$, $V_{\text{CE}} = 0.3\ \text{V}$	$V_{\text{i(on)}}$	0.5	-	1.1	
Input resistor	R_1	7	10	13	kΩ
AC Characteristics					
Transition frequency $I_C = 10\ \text{mA}$, $V_{\text{CE}} = 5\ \text{V}$, $f = 100\ \text{MHz}$	f_{T}	-	150	-	MHz
Collector-base capacitance $V_{\text{CB}} = 10\ \text{V}$, $f = 1\ \text{MHz}$	C_{cb}	-	3	-	pF

¹⁾Pulse test: $t < 300\ \mu\text{s}$; $D < 2\%$

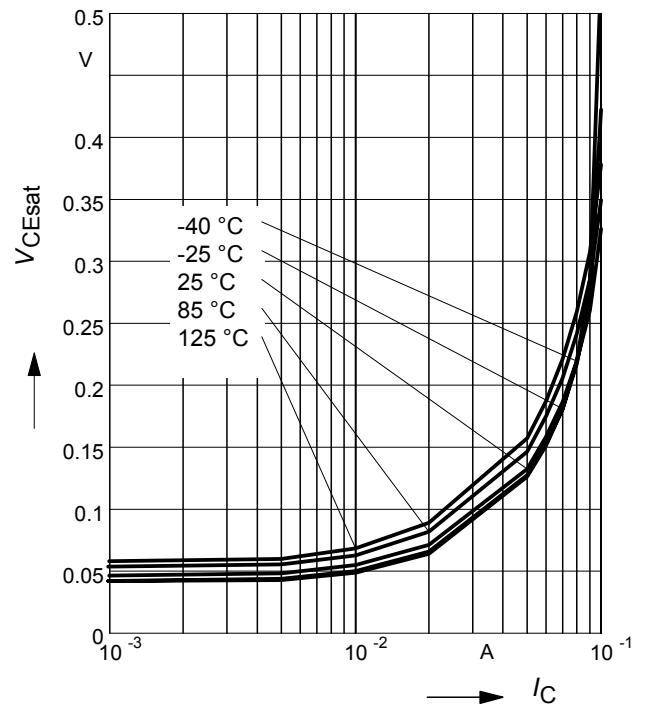
DC current gain $h_{FE} = f(I_C)$

$V_{CE} = 5 \text{ V}$ (common emitter configuration)



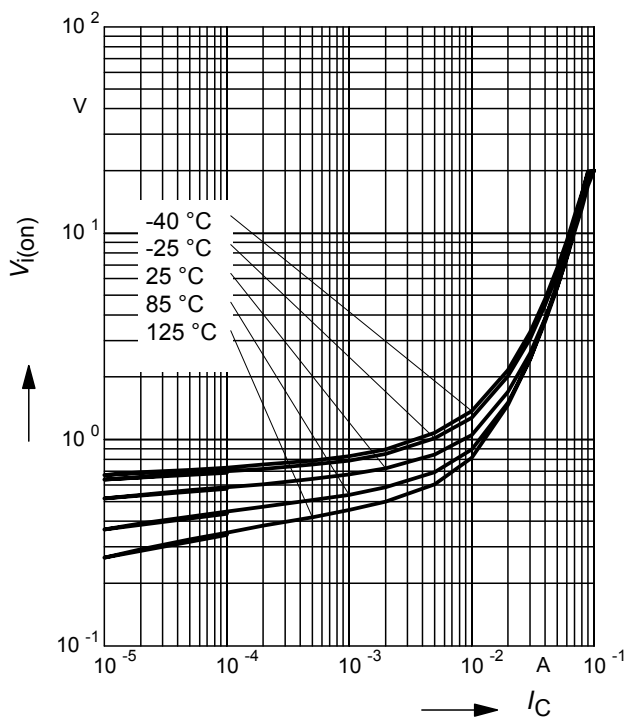
Collector-emitter saturation voltage

$V_{CEsat} = f(I_C)$, $I_C/I_B = 20$



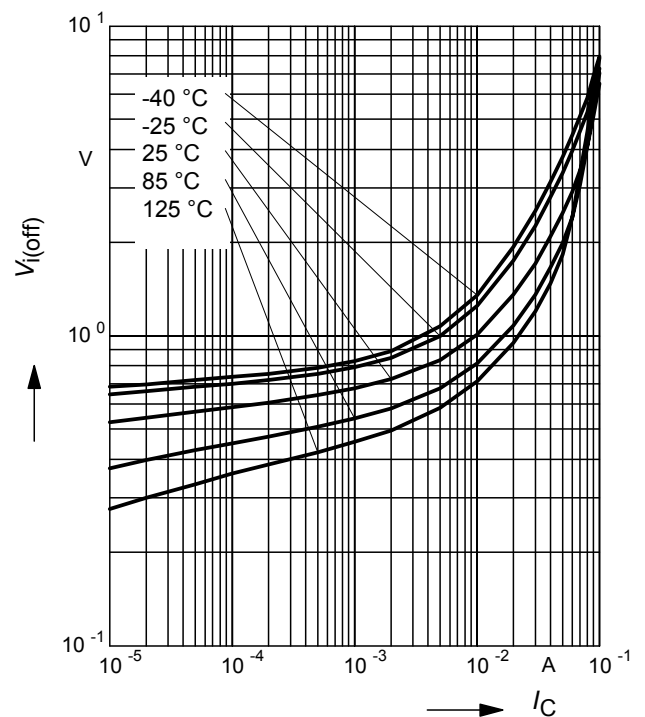
Input on Voltage $V_{i(on)} = f(I_C)$

$V_{CE} = 0.3 \text{ V}$ (common emitter configuration)

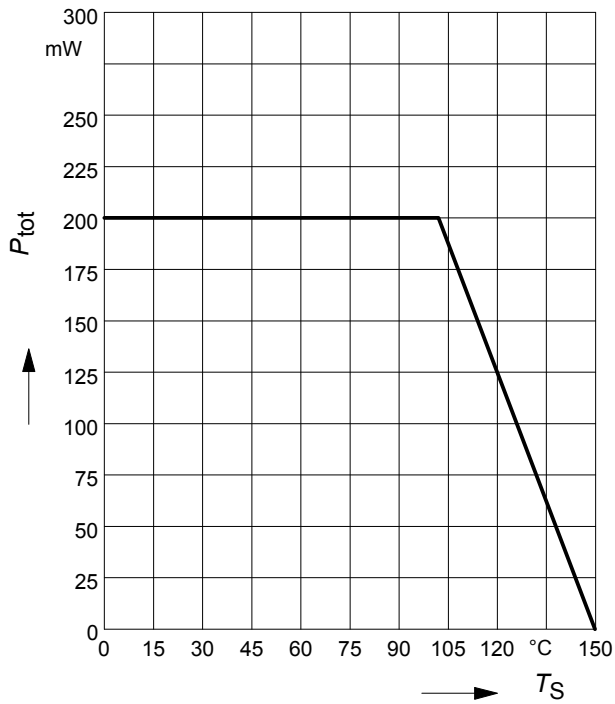


Input off voltage $V_{i(off)} = f(I_C)$

$V_{CE} = 5 \text{ V}$ (common emitter configuration)

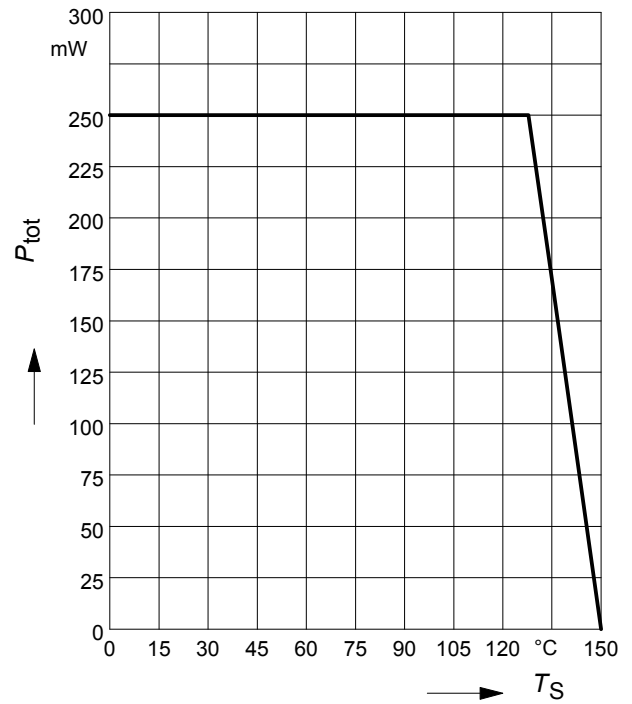


Total power dissipation $P_{\text{tot}} = f(T_S)$



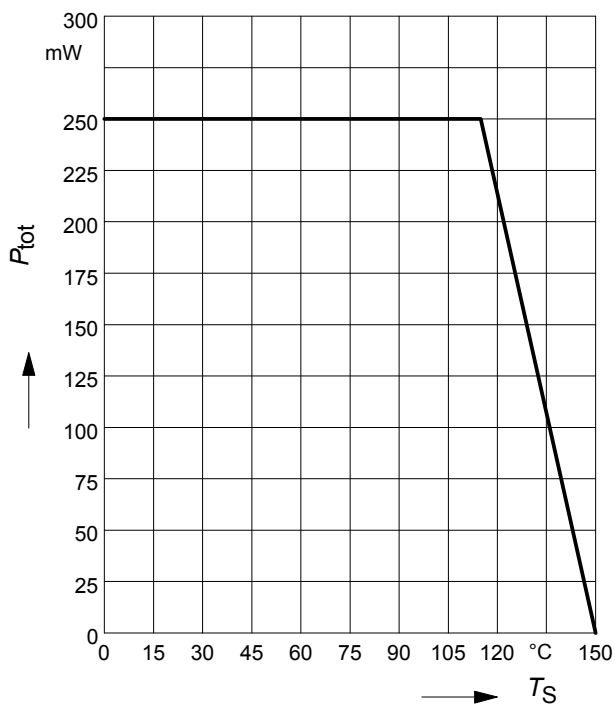
Total power dissipation $P_{\text{tot}} = f(T_S)$

BCR129F



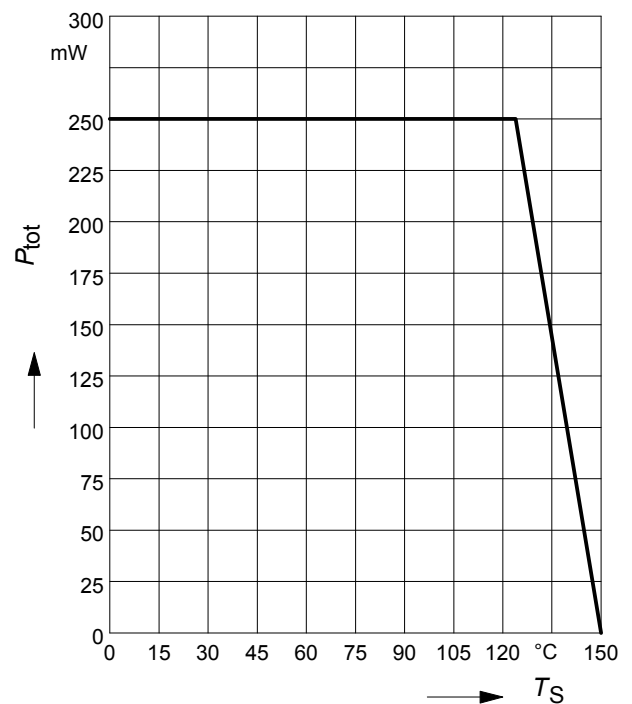
Total power dissipation $P_{\text{tot}} = f(T_S)$

BCR129S



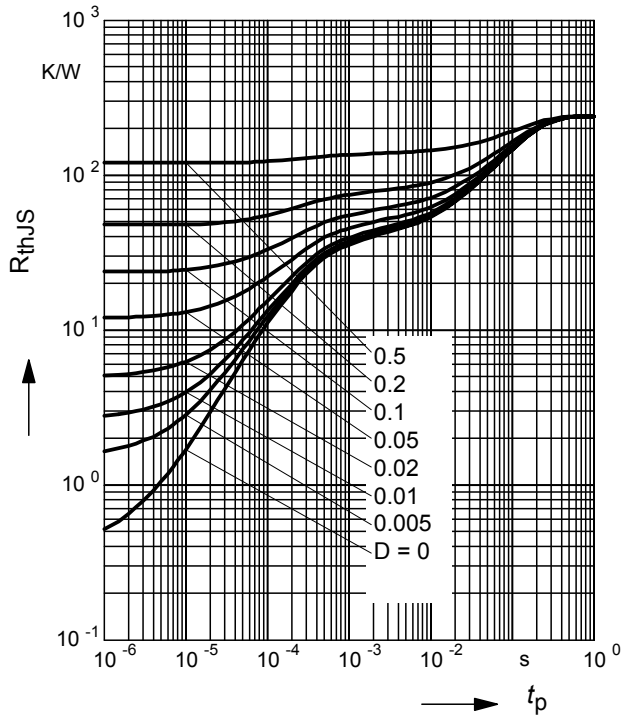
Total power dissipation $P_{\text{tot}} = f(T_S)$

BCR129W



Permissible Pulse Load $R_{thJS} = f(t_p)$

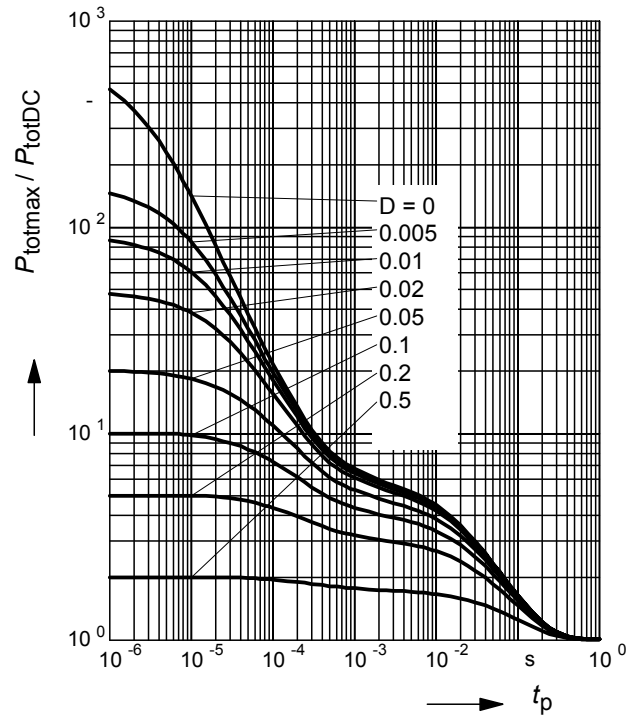
BCR129



Permissible Pulse Load

$$P_{totmax}/P_{totDC} = f(t_p)$$

BCR129



Permissible Puls Load $R_{thJS} = f(t_p)$

BCR129F



Permissible Pulse Load

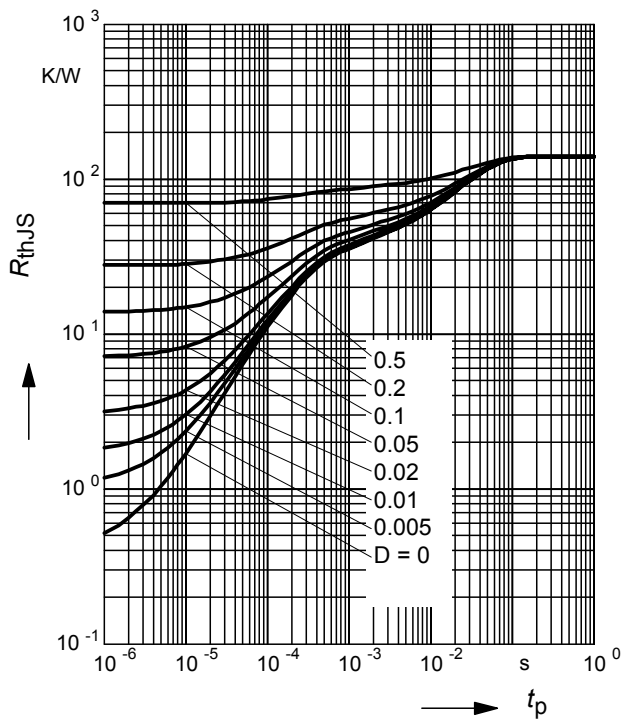
$$P_{totmax}/P_{totDC} = f(t_p)$$

BCR129F



Permissible Puls Load $R_{thJS} = f(t_p)$

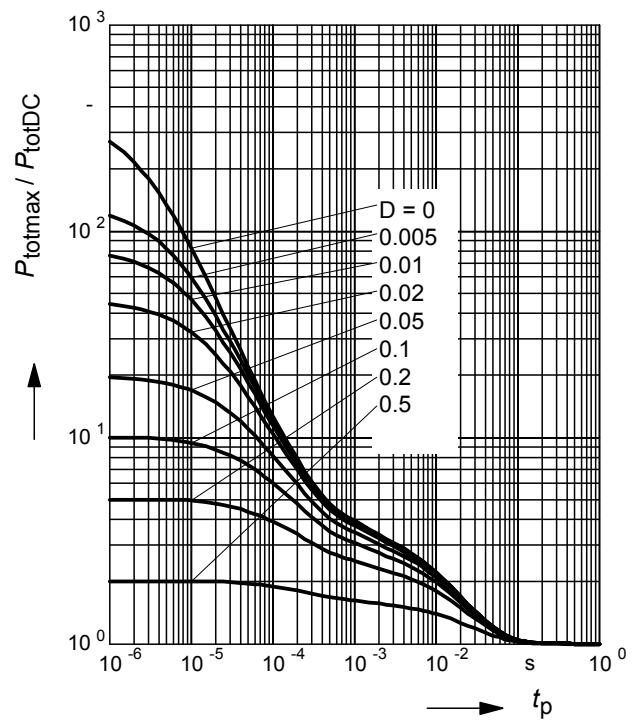
BCR129S



Permissible Pulse Load

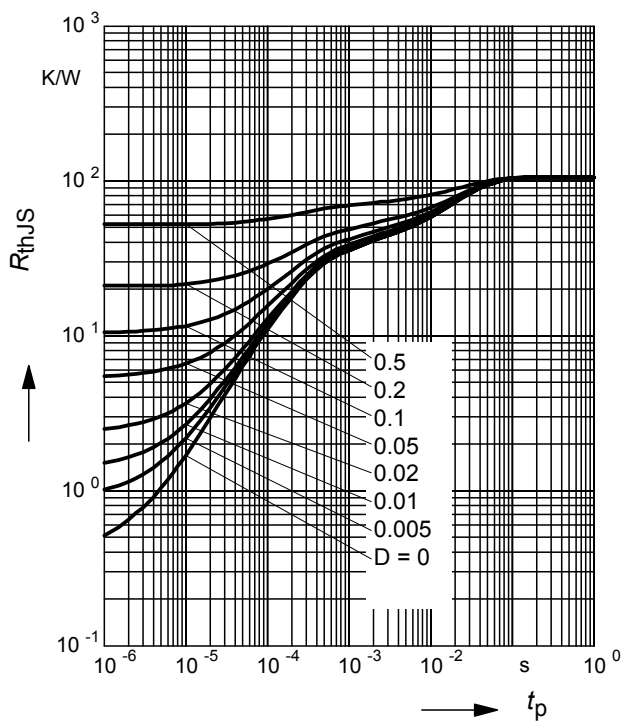
$$P_{totmax}/P_{totDC} = f(t_p)$$

BCR129S



Permissible Puls Load $R_{thJS} = f(t_p)$

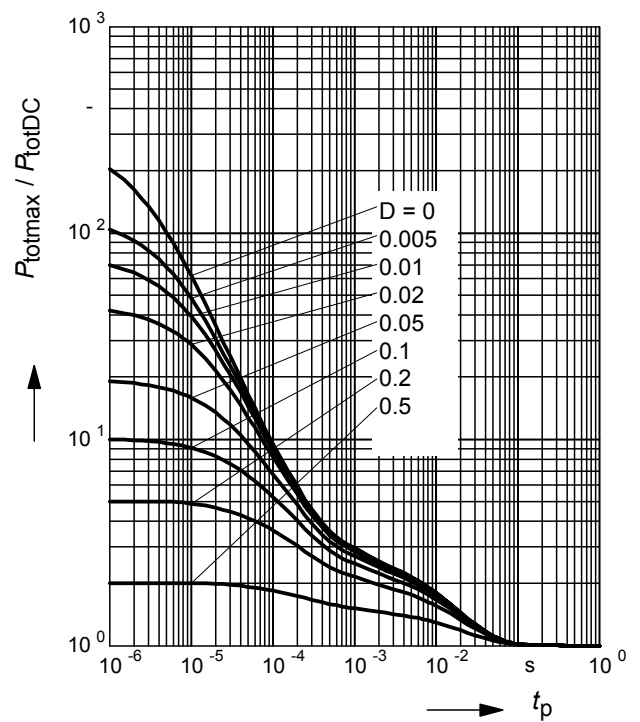
BCR129W

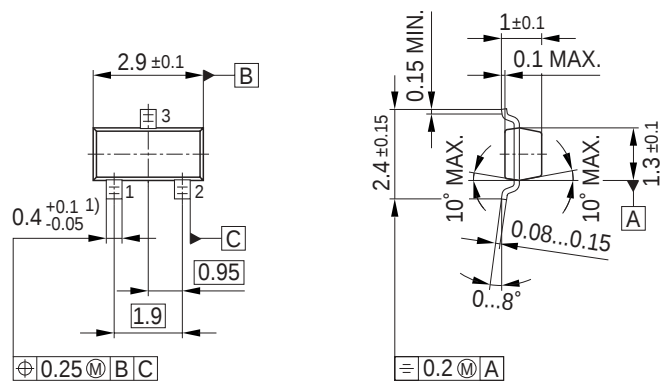


Permissible Pulse Load

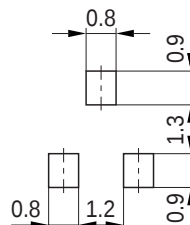
$$P_{totmax}/P_{totDC} = f(t_p)$$

BCR129W



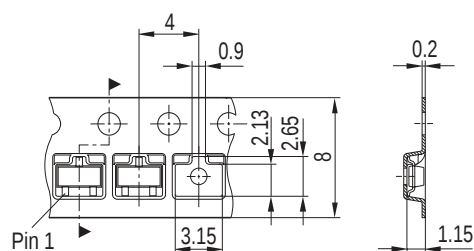


Foot Print

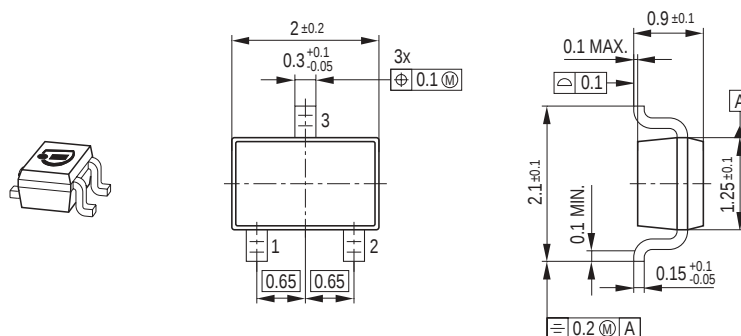


The diagram shows a top-down view of a BCW66 LED package. It is a rectangular component with four pins. The top pin is labeled 'Pin 1'. The package has a central rectangular area containing the text 'EHS' and '2005, June' (Date code (YM)). The Infineon logo is visible in the top right corner. The text 'BCW66' and 'Type code' are located at the bottom right.

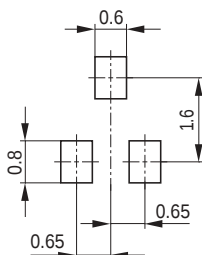
Reel ø180 mm = 3.000 Pieces/Reel
Reel ø330 mm = 10.000 Pieces/Reel



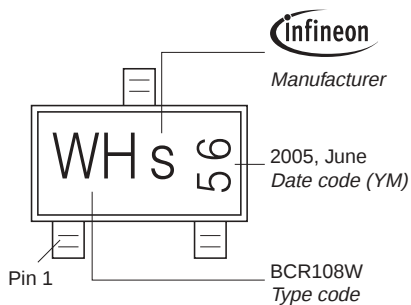
Package Outline



Foot Print

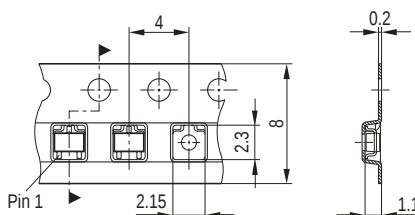


Marking Layout (Example)

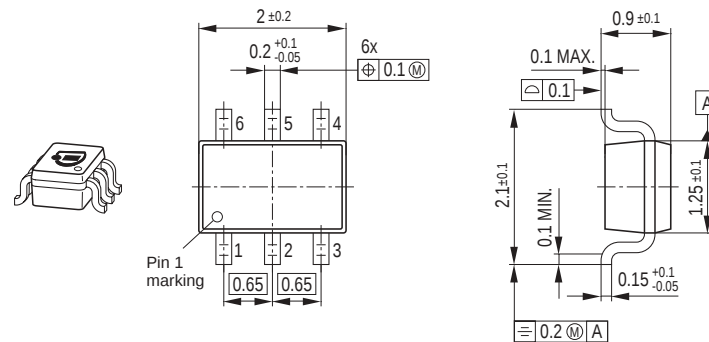


Standard Packing

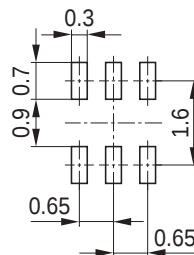
Reel $\varnothing 180$ mm = 3.000 Pieces/Reel
 Reel $\varnothing 330$ mm = 10.000 Pieces/Reel



Package Outline

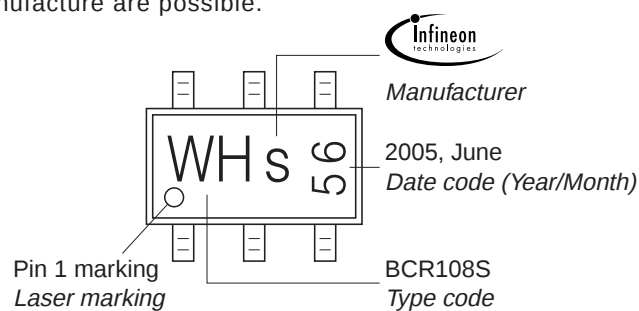


Foot Print



Marking Layout (Example)

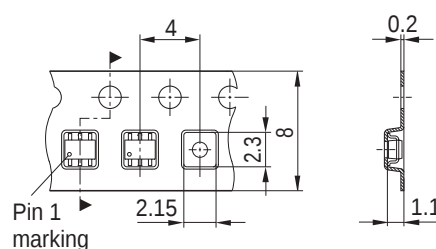
Small variations in positioning of Date code, Type code and Manufacture are possible.



Standard Packing

Reel $\varnothing 180 \text{ mm}$ = 3.000 Pieces/Reel
 Reel $\varnothing 330 \text{ mm}$ = 10.000 Pieces/Reel

For symmetric types no defined Pin 1 orientation in reel.



[illegible]

Technical drawing of a mechanical part with dimensions: 0.4, 0.45, 1.05, and 0.4.

Diagram illustrating the marking on the BCR847BF diode:

- infineon**: Manufacturer
- 1F S**: Type code
- Pin 1**: Cathode

Technical drawing of a mechanical part showing a top view and a side view. The top view includes dimensions: 4, 0.3, 1.2, 1.5, 8, 1.35, and Pin 1. The side view includes dimensions: 0.2 and 0.7.

Edition 2006-02-01

Published by

Infineon Technologies AG

81726 München, Germany

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